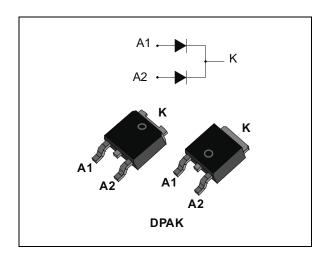
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STPS15L60C

Power Schottky rectifier

Datasheet - production data



Features

- Very small conduction losses
- · Negligible switching losses
- Low forward voltage drop
- Avalanche specification
- ECOPACK[®]2 compliant component for DPAK on demand

Description

Dual center tab Schottky rectifier suited for switched mode power supply and high frequency DC to DC converters.

Packaged in DPAK, this device is intended for use in low voltage, high frequency inverters, freewheeling and polarity protection applications.

Table 1. Device summary

Symbol	Value
I _{F(AV)}	2 x 7.5 A
V _{RRM}	60 V
T _{j(max)}	150 °C
V _F (typ)	0.52 V

Characteristics STPS15L60C

1 Characteristics

Table 2. Absolute ratings (limiting values per diode at 25 °C unless otherwise stated)

Symbol	Parameter	Value	Unit			
V_{RRM}	Repetitive peak reverse voltage		60	V		
I _{F(RMS)}	Forward rms current	10	Α			
1	Average forward current, $\delta = 0.5$, square	$T_{c} = 135 {}^{\circ}\text{C}^{(1)}$	Per diode	7.5	Α	
^I F(AV)	wave		Per device	15	A .	
I _{FSM}	Surge non repetitive forward current $t_p = 10 \text{ ms sinusoidal}$			75	Α	
P _{ARM}	Repetitive peak avalanche power $t_p = 10 \mu s, T_j = 125 \text{ °C}$			265	W	
T _{stg}	Storage temperature range	-65 to +175	°C			
Tj	Maximum operating junction temperature ⁽²⁾			150	°C	

^{1.} Value based on $R_{th(j-c)}$ max (per diode)

Table 3. Thermal resistances

Symbol	Parameter	Value	Unit	
D	Junction to case	Per diode	4	
R _{th(j-c)}		Total	2.4	°C/W
R _{th(c)}	Coupling		0.7	

When the diodes 1 and 2 are used simultaneously:

 $\Delta T_{j}(diode 1) = P(diode 1) \times R_{th(j-c)}(Per diode) + P(diode 2) \times R_{th(c)}$

Table 4. Static electrical characteristics (per diode)

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
. (1)	Reverse leakage current	T _j = 25 °C	$V_R = V_{RRM}$			200	μΑ
'R`'		T _j = 125 °C			45	60	mA
	T _j = 25 °C	. 754			0.62		
		T _j = 125 °C	I _F = 7.5 A		0.52	0.57	
V _F ⁽¹⁾	Forward voltage drep	T _j = 25 °C	1 42 4			0.76	V
V _F ⁽¹⁾ Forward voltage drop	Forward voltage drop	T _j = 125 °C	I _F = 12 A		0.62	0.68	V
		T _j = 25 °C	I _F = 15 A			0.82	
		T _j = 125 °C			0.66	0.72	

^{1.} Pulse test: t_p = 380 μ s, δ < 2%

To evaluate the conduction losses use the following equation:

$$P = 0.32 \text{ x } I_{F(AV)} + 0.027 I_{F}^{2}_{(RMS)}$$



^{2.} $\frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$ condition to avoid thermal runaway for a diode on its own heatsink

STPS15L60C Characteristics

Figure 1. Average forward power dissipation

Figure 2. Average forward current versus ambient temperature (δ = 0.5)(per diode) $I_{\mathsf{F}(\mathsf{AV})}(\mathsf{A})$ R_{th(j-a)}= R_{th(j-c)} R_{th(j-a)}= 70 °C/W T_{amb}(°C)

Figure 3. Normalized avalanche power derating versus pulse duration at T_j = 125 °C

P_{ARM}(tp)
P_{ARM}(10 µs)

1

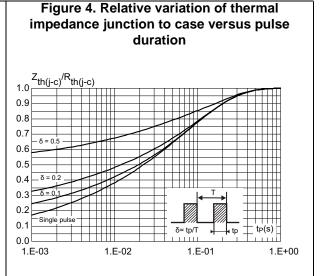
0.01

1

10

100

1000



Characteristics STPS15L60C

Figure 5. Reverse leakage current versus reverse voltage applied (typical values, per diode)

1.E+03

1.E+02

1.E+01

1.E+00

1.E+00

1.E-01

1.E-02

1.E-03

0 5 10 15 20 25 30 35 40 45 50 55 60

Figure 6. Junction capacitance versus reverse voltage applied (typical values, per diode)

1000 C(pF)

1000 F = 1 MHz VRMS = 30 mV - T = 25 °C

1000 1 100 100

Figure 7. Forward voltage drop versus forward current (per diode)

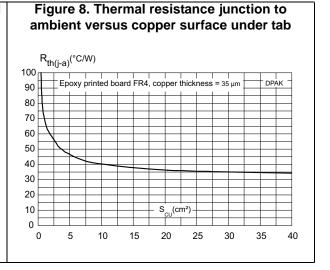
100.0 F(A)

10.0 T_j = 125 °C (typical values)

1.0 T_j = 25 °C (maximum values)

1.0 V_F(V)

0.0 0.2 0.4 0.6 0.8 1.0 1.2 1.4 1.6 1.8 2.0 2.2 2.4 2.6

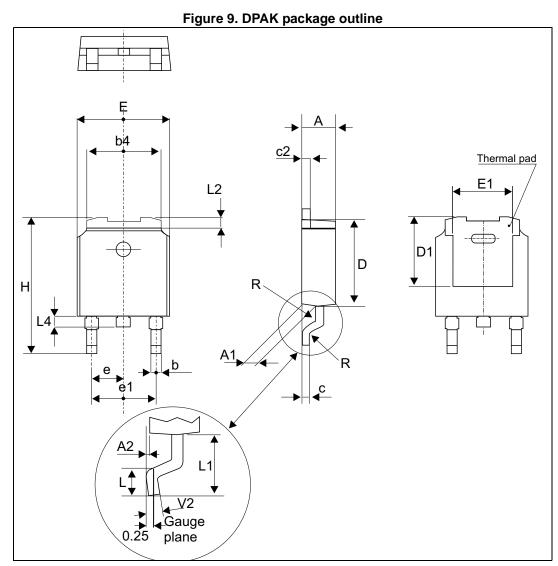


2 Package Information

- Epoxy meets UL94,V0
- Cooling method: by conduction (C)

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

2.1 DPAK package information



Note:

This package drawing may slightly differ from the physical package. However, all the specified dimensions are guaranteed.



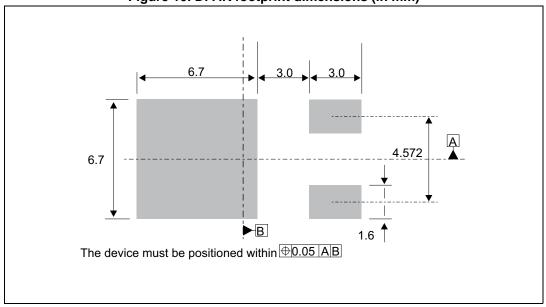
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Package Information STPS15L60C

Table 5. DPAK package mechanical data

	Dimensions					
Ref.	Ref. Mil					
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	2.18		2.40	0.085		0.094
A1	0.90		1.10	0.035		0.043
A2	0.03		0.23	0.001		0.009
b	0.64		0.90	0.025		0.035
b4	4.95		5.46	0.194		0.214
С	0.46		0.61	0.018		0.024
c2	0.46		0.60	0.018		0.023
D	5.97		6.22	0.235		0.244
D1	4.95		5.60	0.194		0.220
E	6.35		6.73	0.250		0.264
E1	4.32		5.50	0.170		0.216
е		2.28			0.090	
e1	4.40		4.70	0.173		0.185
Н	9.35		10.40	0.368		0.409
L	1.00		1.78	0.039		0.070
L2			1.27			0.050
L4	0.60		1.02	0.023		0.040
V2	-8°		+8°	-8°		8°

Figure 10. DPAK footprint dimensions (in mm)



3 Ordering Information

Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS15L60CB	S15L60C	DPAK	0.32 g	75	Tube
STPS15L60CB-TR	S15L60C	DPAK	0.32 g	2500	Tape and reel

4 Revision history

Table 7. Document revision history

Date	Revision	Description of Changes	
27-Jun-2012	2	Automatic revalidation date workflow started.	
07-Jan-2015	3	Updated DPAK package information and reformatted to current standard.	
18-Dec-2015	4	Updated DPAK package information and reformatted to current standard.	

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